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	E MION, PLLC SYLVANIA AVENUE, I	DOLAN, JENNIFER M		
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Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)				
		10/648,276	WATANABE ET AI	L.			
	Office Action Summary	Examiner	Art Unit				
		Jennifer M. Dolan	2813				
Period fo	The MAILING DATE of this communication app or Reply	pears on the cover sheet with the c	orrespondence add	dress			
WHIC - Exter after - If NO - Failu Any r	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DATE of time may be available under the provisions of 37 CFR 1.15 SIX (6) MONTHS from the mailing date of this communication. It is period for reply is specified above, the maximum statutory period vere to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tirn will apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	N. nely filed the mailing date of this co D (35 U.S.C. § 133).	,			
Status							
2a)⊠	Responsive to communication(s) filed on <u>07 No.</u> This action is FINAL . 2b) This Since this application is in condition for allower closed in accordance with the practice under Exercise 1.	action is non-final.		merits is			
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Disposition of Claims							
5)□ 6)⊠ 7)□	4) Claim(s) 28-36 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 28-36 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.						
Applicati	on Papers						
10) 🗌 .	The specification is objected to by the Examine The drawing(s) filed on is/are: a) accent applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	epted or b) objected to by the Edrawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CF	• •			
Priority u	nder 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.							
2) 🔲 Notice 3) 🔲 Inform	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa	te	-152)			

U.S. Patent and Trademark Office PTOL-326 (Rev. 7-05)

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 28, 29, 32, and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,926,586 to Dragone et al. in view of Japanese Patent Publication No. 05-333222 to Oguchi et al. (cited by applicant) and U.S. Patent No. 6,091,870 to Eldada.

Regarding claim 28, Dragone discloses a chip manufacturing method, comprising: forming a plurality of elements on a wafer (figure 5), and cutting out a plurality of chips, each chip including one element (column 2, lines 50-57; column 4, lines 1-16), wherein each element includes a substantially arcuate shape (curved boundaries in central/dotted-line region of figure 5); each chip includes a concave boundary line and a convex boundary line that substantially follow an outline of one of the elements (column 4, lines 4-13), and the concave boundary line of one chip is shaped the same as the convex boundary line of another chip (column 4, lines 4-13; figure 5; if the chips are separated using a nonlinear cut substantially following the contour line of the elements, then it is apparent that the same cut forms the concave boundary of the upper chip and the convex boundary of the lower chip in figure 5).

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Dragone fails to expressly disclose more than one line of elements, but rather only depicts a single line (figure 5). Dragone further fails to teach a step of conducting an optical characteristic test with respect to each element.

Oguchi teaches that it is common and expected in the art of optical elements to form them in a plurality of lines (see figure 2), with each line containing a plurality of elements, such that substantially the entire wafer is filled with optical chip elements (see figure 2). Oguchi further teaches that first the wafer is separated into lines, and then each line is separated into individual chip elements (see paragraph 0014).

Eldada teaches that it is common to perform an optical test on a waveguide structure after cleaving the optical element across the waveguides (column 8, lines 10-15).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to specify that the optical element of Dragone may be formed in more than one line, as suggested by Oguchi, and such that an optical characteristic test is conducted for each element, as suggested by Eldada. The rationale is as follows: A person having ordinary skill in the art would have been motivated to provide the device in more than one line, because it is common and well known in the art of device fabrication to tile devices across the entire usable space of a wafer, in order to increase the number of devices yielded per wafer, as is appreciated by a person having ordinary skill in the art (also see figure 2 of Oguchi et al). Since there appears to be no specific material change, unexpected result, or specific advantage resulting from providing the second line of devices, other than the fact that more devices are provided on the wafer, and since the concept of providing as many 'lines' of devices that may fit on a wafer is well established in the art of semiconductor device manufacturing, it is the Examiner's opinion that the addition of a

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second line of devices to the invention of Dragone constitutes a mere duplication of parts – a modification held by the Court as having no patentable significance. *In re Harza*, 274 F.2d 669, 124 USPQ 378 (CCPA 1960). A person skilled in the art would further desire to conduct an optical characteristic test on each element, because it is standard and reasonable in the art to ensure that a device is functioning properly before packaging the device or putting the device into use. Since Eldada indicates that one might relatively easily test a waveguide optical element to ensure proper functioning after the wafer has been cleaved across the ends of the waveguides (see Eldada, column 8, lines 10-15), and since each element of Dragone in either line form (figure 5) or completely singulated form has exposed or cleaved ends of the waveguides, it is apparent that each element could similarly be tested either before or after singulating each element from the line of elements.

Regarding claim 29, Dragone discloses that the chips are cut using a laser beam (column 4, lines 18-25).

Regarding claim 32, Dragone discloses that dicing is used to cut the straight-line portions of the contours (column 4, lines 18-25; only the curved portions are cut with the laser; also see column 2, lines 5-26).

Regarding claim 33, Dragone discloses that a plate is mounted on at least a portion of the chip (column 5, lines 10-15).

3. Claims 30 and 31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Dragone et al. in view of Oguchi and Eldada, as applied to claim 28, supra, and further in view of U.S. Patent No. 5,776,796 to Distefano et al.

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Dragone fails to teach that ultrasonic vibration or hydraulic pressure can be used to cut the chips from the wafer.

Distefano teaches that laser cutting, ultrasonic vibration, and hydraulic pressure cutting are all well-known and interchangeable means for dicing a chip component (see column 5, lines 19-25).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to specify that the method of Dragone as modified by Oguchi uses ultrasonic vibration or hydraulic pressure for cutting the chips from the wafer, as suggested by Distefano. The rationale is as follows: A person having ordinary skill in the art would have been motivated to use ultrasonic vibration or hydraulic pressure cutting, because Dragone shows that even non-ideal dicing means, such as lasers, are appropriate to use with the methods taught by Dragone (see Dragone, column 4, lines 5-35). Since Distefano teaches that all of a laser, ultrasonic vibrator, or hydraulic jet are well known and recognized equivalent means for dicing a semiconductor wafer, a person skilled in the art could apply any of these to the methods taught by Distefano with a reasonable expectation of success.

4. Claims 34 and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Dragone in view of Oguchi, Eldada, and U.S. Patent No. 5,745,631 to Reinker.

Dragone discloses forming a plurality of elements on a wafer (figure 5); cutting out a plurality of first and second chips, each chip having an optical multiplexer element (see column 1, lines 5-10), where the first and second chips have substantially similar contours having a (figure 5; the "first chip" can be taken as the 'highest chip' and "the second chip" as 'the second-

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highest chip'), wherein each element includes a substantially arcuate shape (curved boundaries in central/dotted-line region of figure 5); each chip includes a concave boundary line and a convex boundary line that substantially follow an outline of one of the elements (column 4, lines 4-13), and the concave boundary line of one chip is shaped the same as the convex boundary line of another chip (column 4, lines 4-13; figure 5; if the chips are separated using a nonlinear cut substantially following the contour line of the elements, then it is apparent that the same cut forms the concave boundary of the upper chip and the convex boundary of the lower chip in figure 5).

Dragone does not teach bonding the chips together using an adhesive and arranging the elements in two or more lines on the wafer. Dragone further fails to teach conducting an optical characteristic test on each element.

Reinker discloses an optical multiplexer formed by stacking chips and flowing an adhesive (column 1, lines 25-45; column 2, lines 1-30; figures 9-11).

Oguchi teaches that it is common and expected in the art of optical elements to form them in a plurality of lines (see figure 2), with each line containing a plurality of elements, such that substantially the entire wafer is filled with optical chip elements (see figure 2). Oguchi further teaches that first the wafer is separated into lines, and then each line is separated into individual chip elements (see paragraph 0014).

Eldada teaches that it is common to perform an optical test on a waveguide structure after cleaving the optical element across the waveguides (column 8, lines 10-15).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the method of Dragone, such that the chips are stacked, as suggested by

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Reinker, and such that multiple lines of elements are formed on the wafer, as suggested by Oguchi. The rationale is as follows: A person having ordinary skill in the art would have been motivated to stack the chips, because doing so allows for the formation of larger scale OEICs, such that a greater number of wavelengths can be accommodated by a multiplexer (see Reinker, column 1, lines 5-30; column 2, lines 25-30; column 5, lines 45-65). A person having ordinary skill in the art would have further been motivated to provide the device in more than one line, because it is common and well known in the art of device fabrication to tile devices across the entire usable space of a wafer, in order to increase the number of devices yielded per wafer, as is appreciated by a person having ordinary skill in the art (also see figure 2 of Oguchi et al). Since there appears to be no specific material change, unexpected result, or specific advantage resulting from providing the second line of devices, other than the fact that more devices are provided on the wafer, and since the concept of providing as many 'lines' of devices that may fit on a wafer is well established in the art of semiconductor device manufacturing, it is the Examiner's opinion that the addition of a second line of devices to the invention of Dragone constitutes a mere duplication of parts – a modification held by the Court as having no patentable significance. In re Harza, 274 F.2d 669, 124 USPO 378 (CCPA 1960). A person skilled in the art would further desire to conduct an optical characteristic test on each element at some point in the production cycle, because it is standard and reasonable in the art to ensure that a device is functioning properly before packaging the device or putting the device into use to save the time and expense of packaging a defective device. Since Eldada indicates that one might relatively easily test a waveguide optical element to ensure proper functioning after the wafer has been cleaved across the ends of the waveguides (see Eldada, column 8, lines 10-15), and since each

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element of Dragone in either line form (figure 5) or completely singulated form has exposed or cleaved ends of the waveguides, it is apparent that each element could similarly be tested either before or after singulating each element from the line of elements.

5. Claim 36 is rejected under 35 U.S.C. 103(a) as being unpatentable over Dragone et al. in view of Oguchi, Eldada, and Reinker as applied to claim 34 above, and further in view of U.S. Patent No. 6,379,909 to Forbes et al.

Dragone fails to suggest that the first chip is cut from a first wafer, and the second chip is cut from a second wafer.

Forbes teaches a stacked chip structure in which the chips can alternately be cut from the same wafer or from different wafers (column 1, lines 20-25).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the method of Dragone as modified by Reinker, such that the chips are cut from different substrates, as suggested by Forbes. The rationale is as follows: A person having ordinary skill in the art would have been motivated to cut the chips from different substrates, because bonding chips cut from different substrates is well-known in the art, and provides the advantages of allowing each device to be fabricated according to its individual performance needs or fabrication processes, as is appreciated by one skilled in the art (see Forbes, column 1, lines 25-60). Since the invention of Dragone as modified by Reinker includes lasers operating at different wavelengths, and accompanying waveguides appropriate to such wavelengths (see Reinker, column 1, lines 5-30, column 2, lines 25-30, column 5, lines 45-65), it would be expected by a person having ordinary skill in the art that the waveguides and lasers from each

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layer of the array should be formed on different substrates, such that the individual emission properties can be optimized.

Response to Arguments

6. Applicant's arguments with respect to claims 28-36 have been considered but are moot in view of the new grounds of rejection.

The Examiner respectfully points out that although the Applicant argues that "a feature of applicant's inventive chip manufacturing method is the inclusion of a step for conducting an optical characteristic test *prior to cutting along the curved cutting paths*," such a limitation is not actually claimed. Instead, the Applicant merely claims that the method comprises a step of conducting the optical characteristic test with respect to each element, which encompasses conducting the test at any time during the manufacturing of the optical element, including before any cleaving occurs, after cleaving into element lines, and after complete singulation of all elements.

Conclusion

- 7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
 - a. U.S. Patent No. 6,393,186 to Deacon discloses testing of an optical waveguide element either before or after fully singulating each element (see figure 13; column 28, lines 27-40).

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b. U.S. Patent No. 5,546,483 to Inoue et al. discloses an optical waveguide device similar to that disclosed by the Applicant and including test structures for conducting optical characteristic tests.

8. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jennifer M. Dolan whose telephone number is (571) 272-1690. The examiner can normally be reached on Monday-Friday 8:30am-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl W. Whitehead, Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Jennifer M. Dolan Examiner Art Unit 2813

jmd

CARL/WHITE/IEAD, JR.
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800